# **Freescale Semiconductor Technical Data**

## Document Number: MHW8342N Rev. 3, 5/2006

**√RoHS** 

# **CATV Amplifier Module**

# Features

- Specified for up to 132-Channel Loading
- **Excellent Distortion Performance** •
- Superior Gain, Return Loss and DC Current Stability over Temperature •
- Silicon Bipolar Transistor Technology •
- Unconditionally Stable Under All Load Conditions •

# Applications

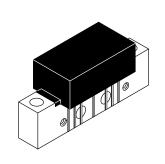
- CATV Systems Operating in the 40 to 870 MHz Frequency Range
- Single Module High Gain Line Amplifier in Cable TV Distribution System •

# Description

- 24 Vdc Supply, 40 to 870 MHz, CATV High Gain Forward Amplifier Module
- Replaced MHW8342. There are no form, fit or function changes with this • part replacement.
- **RoHS** Compliant •



870 MHz 35.5 dB GAIN 132-CHANNEL CATV AMPLIFIER MODULE



CASE 1302-01, STYLE 1

Та	ble	1.	Maximum	Ratings

Table T. Maximum Ratings			
Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V <sub>in</sub>	+ 55	dBmV
DC Supply Voltage	V <sub>CC</sub>	+28	Vdc
Operating Case Temperature Range	T <sub>C</sub>	- 20 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	- 40 to +100	°C

Table 2. Electrical Characteristics (V<sub>CC</sub> = 24 Vdc,  $T_C$  = +30°C, 75  $\Omega$  system unless otherwise noted)

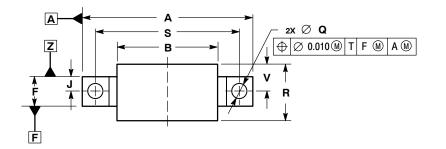
Characteris	Symbol	Min	Тур	Max	Unit	
Frequency Range		BW	40	_	870	MHz
Power Gain	50 MHz 870 MHz	G <sub>p</sub>	33.2 34	34 35.5	34.8 37	dB
Slope	40 - 870 MHz	S	0.5	1.5	2.75	dB
Gain Flatness (Peak To Valley)		G <sub>F</sub>	_	0.3	0.8	dB
Return Loss — Input		IRL				dB
(Z <sub>o</sub> = 75 Ohms)	40-80 MHz		22	28	_	
	80-320 MHz		18	25	—	
	320-640 MHz		16	22		
	640-870 MHz		14	19		
Return Loss — Output		ORL				dB
(Z <sub>o</sub> = 75 Ohms)	40-80 MHz		22	28	—	
	80-240 MHz		19	25	_	
	240-640 MHz		17	22	_	
	640-870 MHz		15	22		

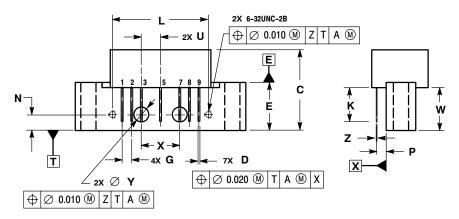


Table 2. Electrical Characteristic	<b>s</b> (V <sub>CC</sub> = 24 Vdc,	$T_{C} = +30^{\circ}C,$	75 $\Omega$ system unless	otherwise noted) (continued)
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Characteristic	Symbol	Min	Тур	Max	Unit	
Composite Second Order						dBr
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CSO <sub>79</sub>	_	- 65	- 60	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CSO <sub>112</sub>	—	- 55	- 50	
(Vout = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CSO <sub>132</sub>	—	- 48	- 44	
Cross Modulation Distortion						dBc
(V <sub>out</sub> = +44 dBmV, FM = 55.25 MHz)	79-Channel FLAT	XMD <sub>79</sub>	—	- 63	- 60	
(V <sub>out</sub> = +44 dBmV, FM = 55.25 MHz)	112-Channel FLAT	XMD <sub>112</sub>	—	- 56	-52	
(V <sub>out</sub> = +44 dBmV, FM = 55.25 MHz)	132-Channel FLAT	XMD <sub>132</sub>	—	- 56	-50	
Composite Triple Beat						dBc
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CTB <sub>79</sub>	—	- 64	- 62	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CTB <sub>112</sub>	—	- 54	- 51	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CTB <sub>132</sub>	—	- 50	- 46	
Noise Figure	50 MHz	NF	_	3.5	4.5	dB
	550 MHz		_	4.5	_	
	870 MHz		—	5.5	6.5	
DC Current		I <sub>DC</sub>	310	325	350	mA

# PACKAGE DIMENSIONS





NOTES: 1. DIMENSIONS ARE IN INCHES. 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INC	HES	MILLIMETERS		
DIM	MIN	MIN MAX		MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
E	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100	BSC	2.540	BSC	
J	0.156	6 BSC	3.96	2 BSC	
K	0.315	0.355	8.001	9.017	
L	1.000	) BSC	25.400 BSC		
Ν	0.165	165 BSC 4.191 BS		BSC	
Ρ	0.100 BSC		2.540 BSC		
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500	BSC	38.100 BSC		
U	0.200	BSC	5.080 BSC		
۷		0.250		6.350	
W	0.435		11.049		
X	0.400	BSC	10.16	0 BSC	
Y	0.152	0.163	3.861	4.140	
Ζ	0.009	0.011	0.229	0.279	

STYLE 1: PIN 1. RF INPUT 2. GROUND 3. GROUND 4. DELETED 5. VDC 6. DELETED 7. GROUND 8. GROUND 9. RF OUTPUT

CASE 1302-01 ISSUE E

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